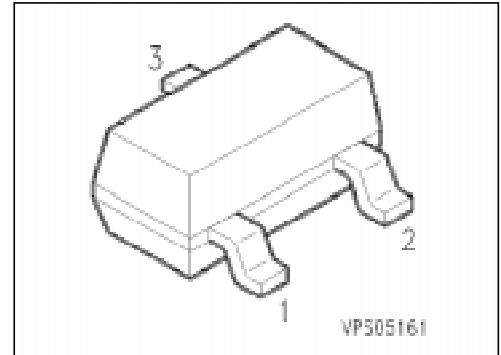


## Silicon Schottky Diodes

## BAT 68 ...

- For mixer applications in the VHF/UHF range
- For high-speed switching

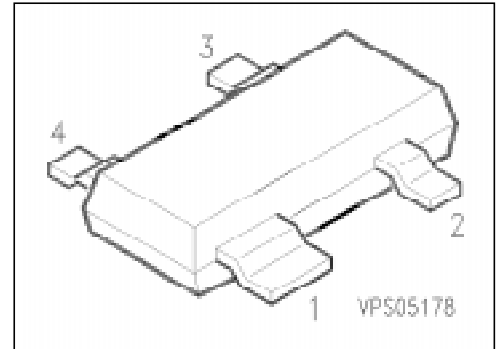


**ESD:** Electrostatic discharge sensitive device, observe handling precautions!

| Type      | Marking | Ordering Code (tape and reel) | Pin Configuration | Package <sup>1)</sup> |
|-----------|---------|-------------------------------|-------------------|-----------------------|
| BAT 68    | 83      | Q62702-A926                   |                   | SOT-23                |
| BAT 68-04 | 84      | Q62702-A4                     |                   |                       |
| BAT 68-05 | 85      | Q62702-A15                    |                   |                       |
| BAT 68-06 | 86      | Q62702-A19                    |                   |                       |

<sup>1)</sup> For detailed information see chapter Package Outlines.

- For mixer applications in the VHF/UHF range
- For high-speed switching



**ESD: Electrostatic discharge sensitive device, observe handling precautions!**

| Type      | Marking | Ordering Code (tape and reel) | Pin Configuration | Package <sup>1)</sup> |
|-----------|---------|-------------------------------|-------------------|-----------------------|
| BAT 68-07 | 87      | Q62702-A44                    |                   | SOT-143               |

### Maximum Ratings per Diode

| Parameter                                  | Symbol    | Values         | Unit |
|--|-----------|----------------|------|
| Reverse voltage                            | $V_R$     | 8              | V    |
| Forward current                            | $I_F$     | 130            | mA   |
| Power dissipation, $T_s \leq 60\text{ °C}$ | $P_{tot}$ | 150            | mW   |
| Junction temperature                       | $T_j$     | 150            | °C   |
| Storage temperature range                  | $T_{stg}$ | - 55 ... + 150 |      |

### Thermal Resistance

|                                  |              |            |     |
|----------------------------------|--------------|------------|-----|
| Junction - ambient <sup>2)</sup> | $R_{th\ JA}$ | $\leq 750$ | K/W |
| Junction - soldering point       | $R_{th\ JS}$ | $\leq 590$ |     |

<sup>1)</sup> For detailed information see chapter Package Outlines.

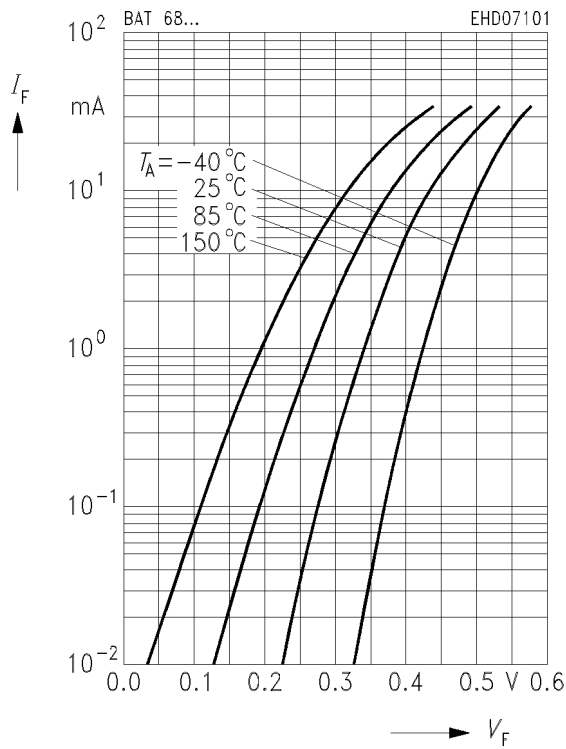
<sup>2)</sup> Package mounted on alumina 15 mm × 16.7 mm × 0.7 mm.

**Electrical Characteristics per Diode**  
at  $T_A = 25\text{ °C}$ , unless otherwise specified.

| Parameter   | Symbol   | Values |        |            | Unit          |
|---|----------|--------|--------|------------|---------------|
|   |          | min.   | typ.   | max.       |               |
| Breakdown voltage<br>$I_R = 10\text{ }\mu\text{A}$                              | $V_{BR}$ | 8      | –      | –          | V             |
| Reverse current<br>$V_R = 1\text{ V}$<br>$V_R = 1\text{ V}, T_A = 60\text{ °C}$ | $I_R$    | –<br>– | –<br>– | 0.1<br>1.2 | $\mu\text{A}$ |
| Forward voltage <sup>1)</sup><br>$I_F = 1\text{ mA}$<br>$I_F = 10\text{ mA}$    | $V_F$    | –<br>– | –<br>– | 340<br>500 | mV            |
| Diode capacitance<br>$V_R = 0, f = 1\text{ MHz}$                                | $C_T$    | –      | –      | 1          | pF            |
| Differential forward resistance<br>$I_F = 5\text{ mA}, f = 10\text{ kHz}$       | $r_f$    | –      | –      | 10         | $\Omega$      |

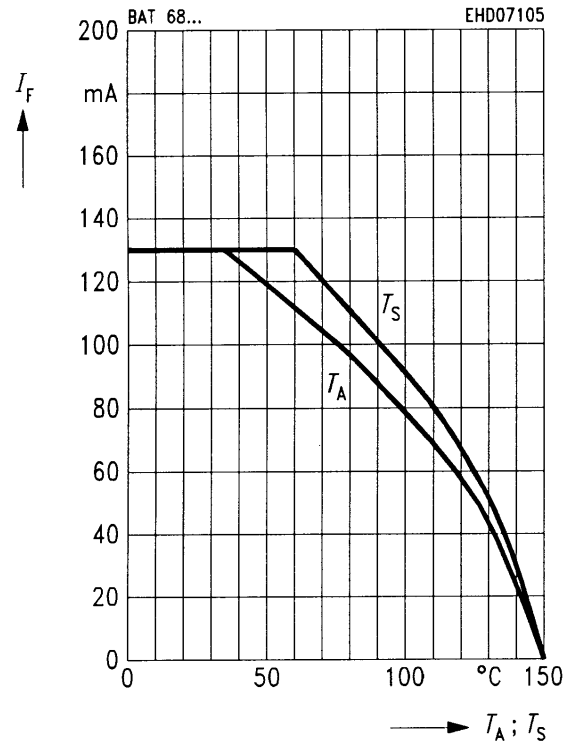
<sup>1)</sup> Forward voltage matching, types -04, -05, -06, -07  $I_F = 10\text{ mA}$ ,  $\Delta V_F = 20\text{ mV}$  max.

**Forward current  $I_F = f(V_F)$**



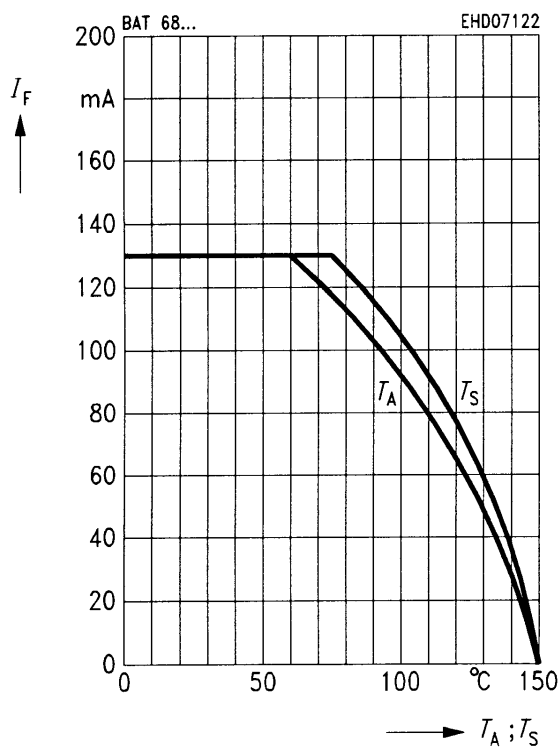
**Forward current  $I_F = f(T_S, T_A^*)$**

\*Package mounted on alumina  
BAT 68-04, -05, -06, -07

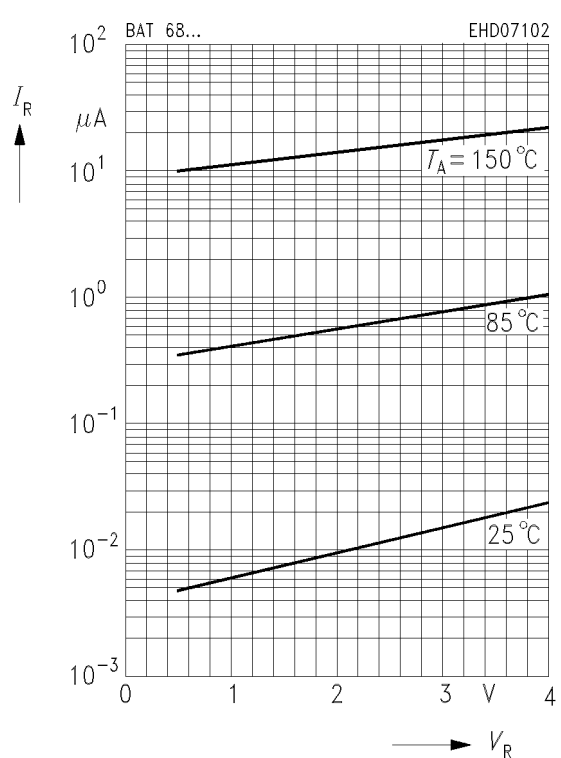


**Forward current  $I_F = f(T_S; T_A^*)$**

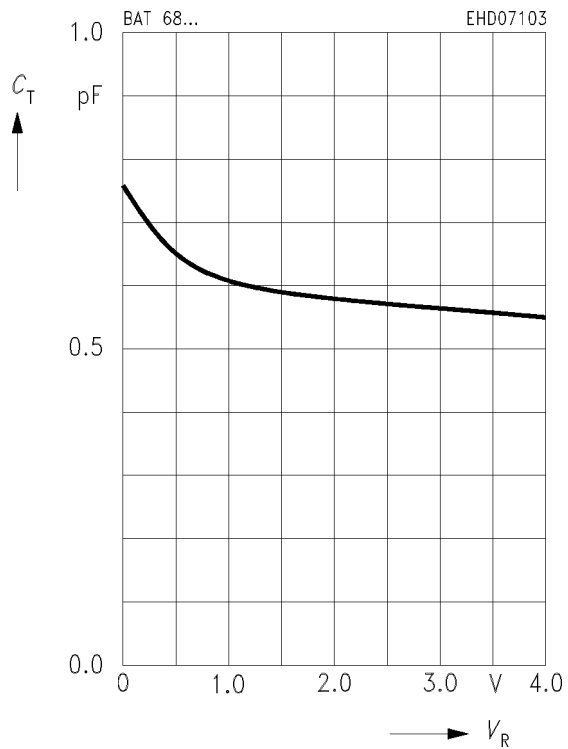
\*Package mounted on alumina  
BAT 68



**Reverse current  $I_R = f(V_R)$**



**Diode capacitance  $C_T = f(V_R)$**   
 $f = 1 \text{ MHz}$



**Differential forward resistance  $r_f = f(I_F)$**   
 $f = 10 \text{ kHz}$

